

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

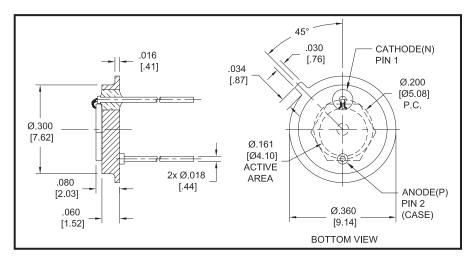
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







PHOTODIODE 13 mm<sup>2</sup> UVG12



## **FEATURES**

- · Circular active area
- Ideal for 193-400 nm detection
- 100% internal QE
- · No cap for maximum responsivity
- Sacrificial cap taped on for shipping purposes

Dimensions are in inch [metric] units.

## **ELECTRO-OPTICAL CHARACTERISTICS AT 25°C**

PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Active Area	Ø 4.1 mm		13.2		mm <sup>2</sup>
Responsivity, ${\cal R}$	@ 254 nm	0.105	0.115	0.125	A/W
Shunt Resistance	V <sub>F</sub> = ± 10 mV	100	1000		Mohm
Reverse Breakdown Voltage, V <sub>R</sub>	I <sub>R</sub> = 1 μA		9		Volts
Capacitance, C	V <sub>R</sub> = 0 V		3	7	nF
Rise Time	V <sub>R</sub> = 0 V			4	μsec

## THERMAL PARAMETERS

STORAGE AND OPERATING TEMPERATURE RANGE	
Storage Temperature Range	-20° TO 80°C
Maximum Junction Temperature	80°C
Lead Soldering Temperature <sup>1</sup>	240°C

<sup>&</sup>lt;sup>1</sup>0.0625" from case for 10 seconds.

Shipped with temporary cover to protect photodiode and wire bond. Review Opto Diode "Handling Precautions for IRD Detectors" prior to removing cover.



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